

Appl. No. : 10/661,414
Filed : September 12, 2003

AMENDMENTS TO THE SPECIFICATION

Please amend paragraph [0001] as follows:

[0001] This application is a continuation of prior U.S. Patent Application No. 09/879,604, filed on June 12, 2001, now U.S. Patent No. 6,653,675, issued on November 25, 2003, which is a divisional of prior U.S. Patent Application No. 09/252,314, filed February 18, 1999, entitled METHOD OF FABRICATING A DUAL GATE DIELECTRIC, now 6,383,861 issued on May 07, 2002.

Please replace the Title as follows:

Multiple Thickness Gate Dielectric Layers